

8-BIT SUCCESSIVE APPROXIMATION REGISTER (SAR) ANALOG TO DIGITAL (ADC) LOGIC DESIGN

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Abstract – A 8-bit SAR logic of SAR ADC has been realized in a HP 0.5 μ m SCN3M Complementary Metal Oxide Semiconductor (CMOS) process. The power consumption is 3.59mW with resolution of 8-bit. The speed is 125KHz with the supply voltage of 5V. The SAR logic has been designed in custom design approach.

Keyword: Successive approximation register (SAR) Analog to digital converter (ADC), SAR logic, power consumption, CMOS, resolution.

1. INTRODUCTION

The successive approximation register analog to digital (SAR ADC) is one of the most widely used types of ADC compared with other ADC architecture. SAR ADC provides number of advantages [4]. First, low power consumption because only one comparator in the whole system. Second, high resolution and accuracy can be achieved using capacitor array during data conversion. Third, has more complex circuitry than digital-ramp ADC but shorter conversion time. In addition, SAR ADC has a fixed value of conversion time.

In this paper, development of 8-bit SAR ADC digital control logic is presented.

1.1 SAR ADC Architecture

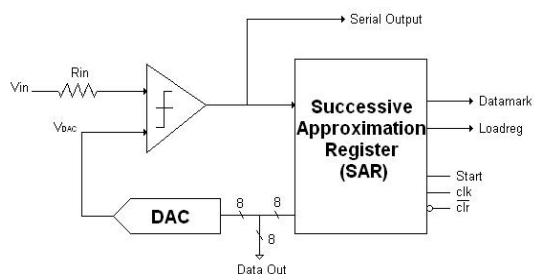


Figure 1: SAR ADC Block Diagram

The block diagram of Successive Approximation Register (SAR) Analog-to-Digital (ADC) is shown in Figure 1. The SAR ADC consists of three modules, which are comparator, SAR control logic and Digital-to-Analog Converter (DAC). The implementation progresses of the SAR like a

binary search algorithm to arrive at the final digital output with an error of no more than $0.5V_{LSB}$ [3].

At starting of a conversion, all the bits of SAR are reset to “0” except the MSB which is set to “1”. The SAR output drives the internal DAC. If the DAC output is greater than the analog input, this bit in the SAR is reset, otherwise it is left set. The process is repeated with each bit in turn. When all the bits have been set, tested, and reset or not as appropriate, the contents of the SAR correspond to the value of the analog input, and the conversion is complete. The end of conversion is indicated by a loadreg which means that the data will be loaded to register. An N-bit conversion takes N steps.

2. SAR LOGIC DESIGN

2.1. Block Diagram of SAR Logic

The successive approximation logic is based on the shift register and register. Figure 2 shows the block diagram of the SAR logic. SAR logic consists of 10 bit shift register, register low to high and code register.

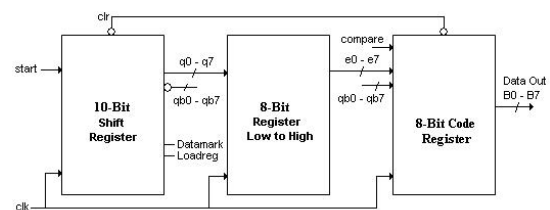


Figure 2: Block Diagram of SAR Logic

2.2. Shift Register

A shift registers are used to store information in the register one bit at a time. The type of shift register is serial in/parallel out and acts on the stored information in a register by shifting its contents to the right. The block diagram of shift register is shown in Figure 3.

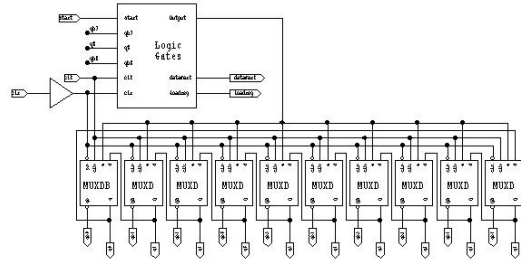


Figure 3: 10-Bit Shift Register

The block diagram consists of control logic gates (Appendix B) and shift register. The internal structure of shift register consists of 2 to 1 multiplexer and D flip-flop. On the last register (10th register) has an inverter in the structure as shown in Figure 4. The inverter will converted the input bit from 0 to 1 or otherwise. The timing diagram of shift register is illustrated in Figure 5. The first state, S12, is used to clear all bit at the register. At state 11, datamark will be set which means a start of a conversion. Sampling occurs at state 10 and the 10th register (q9) will be set. States 9 to 1 are bit shifting states where bits 8 through 1 are determined in parallel. The 8 bit code is ready during state 12 of the next conversion cycle and so that loadreg will be set.

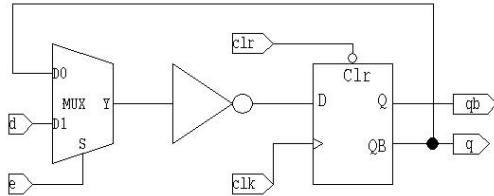


Figure 4: Structure of shift register with inverter.

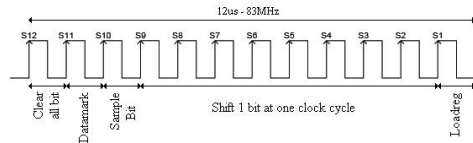


Figure 5: Timing diagram for operation of shift register

2.3. Register Low to High

A register is a temporary storage device. The type of register used is parallel register. The contents of the register are called a WORD. For an 8 bit register is an 8-bit word. The schematic circuit of 1-bit register low-to-high is shown in Figure 6 and 8-bit register in Figure 7. This circuit will receive data and transfer it at the proper time. It is also improved the signal flows through it from low signal to the high signal. Truth table for the operation of register is shown in Table 1.

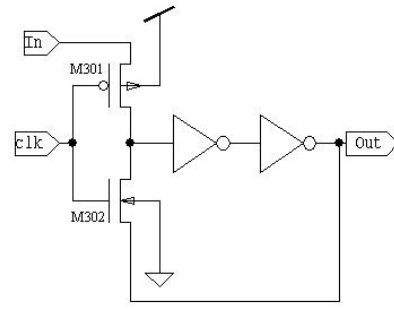


Figure 6: 1-Bit Register Low-to-High

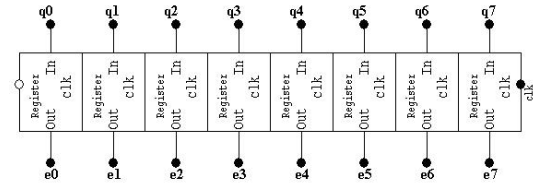


Figure 7: 8-Bit Register Low-to-High

Table 1: Truth Table for Register low-to-high

Clock	PMOS	NMOS	Out
Rising	OFF	ON	Stay
Falling	ON	OFF	In

2.4. Code Register

The implementation of code register is illustrated in Figure 8. It consists of register and NAND gate. NAND gate used to improve the conversion time. The internal structure of a register is shown in Figure 9. It is composed by a D Flip-flop with a multiplexer (MUX). MUX will control which one of the two data input, D0 and D1 will be transmitted to the output. D0 and D1 are selected from the output of previous flip-flops stage and the output from the comparator respectively. Truth table for flip-flop outputs is shown in Table 2.

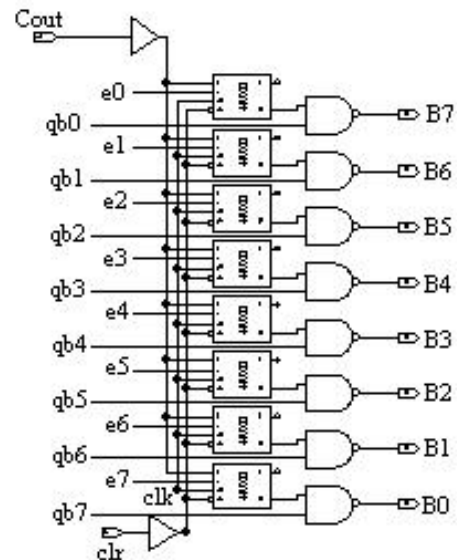


Figure 8: 8-Bit code register

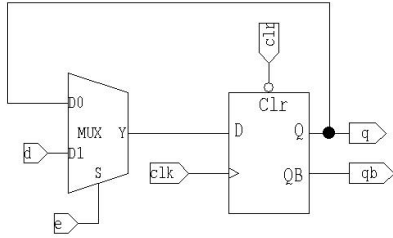


Figure 9: Structure of shift register

Table 2: Truth Table for Flip-Flop output

Select, <i>s</i>	Operation
1	Comparator output, <i>DI</i>
0	Memorize present stage, <i>D0</i>

3. RESULTS AND DISCUSSION

The 8-bit SAR ADC logic was designed in a HP 0.5 μ m SCN3M technology. The SAR logic was evaluated in terms of power consumption, resolution and speed. The whole structure of the schematic is shown in Figure 10 and the internal structure of register in Figure 11.

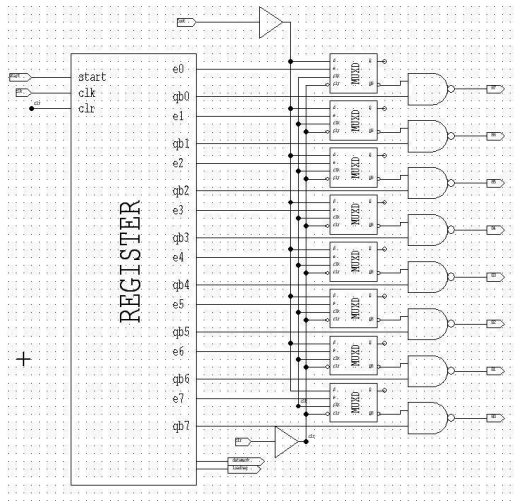


Figure 10: Structure of SAR Logic

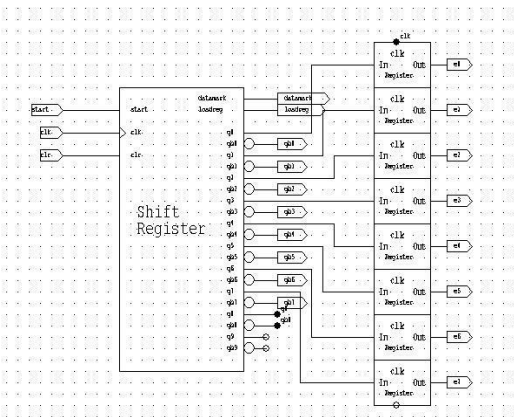


Figure 11: Structure in module of register

3.1 Shift Register Characteristics

The type of shift register is serial in/parallel out or SIPO shift register and shift in right direction. The waveform of shift register is shown in Figure 12.

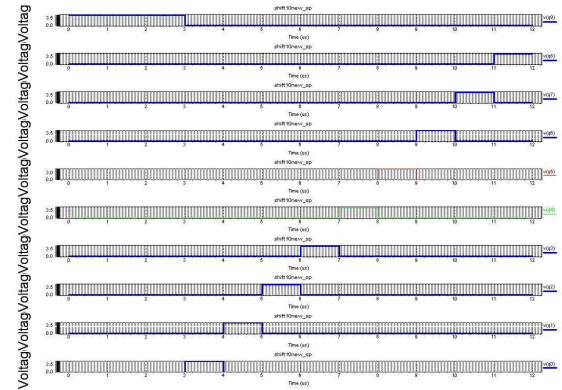


Figure 12: Output waveform of shift register

The propagation delay of shift register is 1 μ s. This delay is mentioned in term of clock cycle time. The risetime and falltime was found when the shift register run at the voltage of 1V which is 14.84ns and 6.11ns respectively. The power consumption for the shift register is 3.06mW.

3.2 Register Low to High Characteristics

Figure 13 shows the output waveform of register. The input of the register is actually combined from the output of shift register before. It shows that time taken for a bit stored in the register is 0.5 μ s and a bit stay high until the falling edge of the clock. The propagation delay is also same with the shift register where 1 μ s delay and the power consumption included of shift register is 2.78mW.

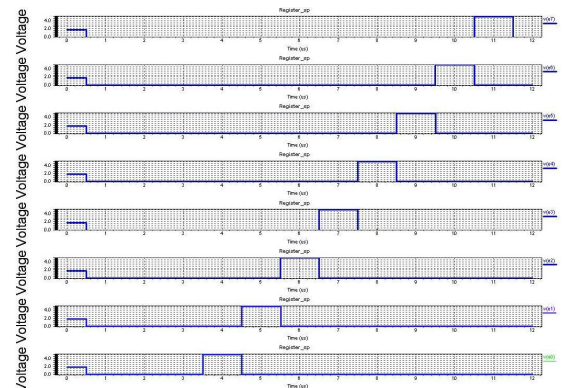


Figure 13: Output waveform of register

3.3 Code Register Characteristics

The output waveform of code register is mentioned in Figure 14. The code register is used as a storage register where it stored the data from comparison output from the comparator. The specification of code register is mentioned in SAR Logic characteristics.

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APPENDIX A

Transistors	Size of Width (λ)		
	Size 1	Size 2	Size 3
BUFFER			
M1,M2	18	10	10
M3,M4	28	20	15
DFF			
M7,M8,M11,M12 M20,M21,M24 M12,M17,M16	15	10	10
M26,M29,M27	22	15	15
M1,M2,M3,M4	6	5	5
M5,M6	17	15	10
M9,M10	14	10	10
M18,M19,M23	16	15	10
M22,M25	24	20	15
M14	9	5	5
M28	27	20	15
M15	11	10	5
MUX			
M11,M12 M6,M7,M8,M9,M10	28	20	15
M1,M2,M3,M4,M5	21	15	10
NAND3/NAND2/NOR2/INV			
M1,M2,M3,M4,M5,M6	28	20	15
REGISTER			
M301,M302	6	6	5

* Size of length (L) is all same for the transistors which are 2λ

APPENDIX B

